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Vishay Siliconix

## Automotive N-Channel 60 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V <sub>DS</sub> (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0030			
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = 4.5 \text{ V}$	0.0047			
I <sub>D</sub> (A)	278			
Configuration	Single			
Package	PowerPAK SO-8L			

#### **FEATURES**

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



	O <sup>D</sup>
<del> -</del>	<b>-</b>
G O	<b>†</b> ]
N-Channel MOSFET	o <sub>s</sub>

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V <sub>DS</sub>	60	V		
Gate-source voltage		$V_{GS}$	± 20	V		
Continuous drain current	T <sub>C</sub> = 25 °C a	1	278			
	T <sub>C</sub> = 125 °C	- I <sub>D</sub>	166			
Continuous source current (diode conduction)	I <sub>S</sub>	454	Α			
Pulsed drain current <sup>b</sup>		I <sub>DM</sub>	575			
Single pulse avalanche current	L = 0.1 mH	l <sub>AS</sub>	48			
Single pulse avalanche energy	L=0.1 mh	E <sub>AS</sub>	115	mJ		
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	500	W		
	T <sub>C</sub> = 125 °C	$P_{D}$	166	VV		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C		
Soldering recommendations (peak temperature		260	C			

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount c	$R_{thJA}$	42	°C/W	
Junction-to-case (drain)		$R_{thJC}$	0.30	C/VV	

#### Notes

- a. Package limited
- b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static	•			l		•	L
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0$ , $I_D = 250 \mu A$		60	-	-	V
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	· V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.5	2.0	2.5	V
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 60 V	-	-	1	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 60 V, T <sub>J</sub> = 125 °C	-	-	50	μA
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 60 V, T <sub>J</sub> = 175 °C	-	-	250	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 \text{ V}$	30	-	-	Α
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 15 A	-	0.0026	0.0030	
Duning anyone are state unalistance 2	Б	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 15 A, T <sub>J</sub> = 125 °C	-	-	0.00516	
Drain-source on-state resistance a	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 15 A, T <sub>J</sub> = 175 °C	-	-	0.0065	Ω
		V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 15 A	-	0.0036	0.0047	
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 10 A	-	75	-	S
Dynamic <sup>b</sup>					•	•	•
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	-	3915	5485	pF
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$		-	1780	2500	
Reverse transfer capacitance	C <sub>rss</sub>			-	65	95	
Total gate charge <sup>c</sup>	Qg			-	56	84	
Gate-source charge c	$Q_{gs}$	V <sub>GS</sub> = 10 V	$V_{DS} = 30 \text{ V}, I_{D} = 10 \text{ A}$	-	13	-	nC
Gate-drain charge c	Q <sub>gd</sub>				5	-	1
Gate resistance	$R_{g}$		f = 1 MHz		1.3	2.0	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	13	20	
Rise time <sup>c</sup>	t <sub>r</sub>	V <sub>DD</sub> =	$V_{DD} = 30 \text{ V}, \text{ R}_L = 3.0 \Omega$ $I_D \cong 10 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		4	6	- ns
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 10 \text{ A},$			34	50	
Fall time <sup>c</sup>	t <sub>f</sub>				6	9	
Source-Drain Diode Ratings and Chara	acteristics <sup>b</sup>						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	575	Α
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> =	I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0 V		-	1.1	V
Body diode reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 8 A, di/dt = 100 A/μs		-	54	108	ns
Body diode reverse recovery charge	Q <sub>rr</sub>			-	64	128	nC
Reverse recovery fall time	t <sub>a</sub>			-	26	-	
Reverse recovery rise time	t <sub>b</sub>			-	30	-	ns
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	2.0	-	Α

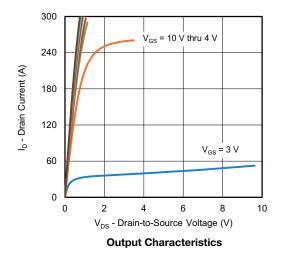
#### Notes

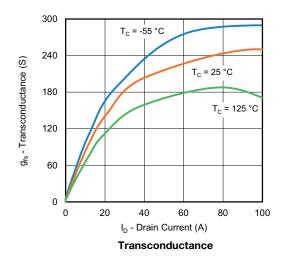
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

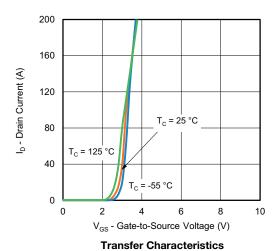
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

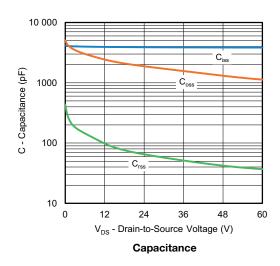


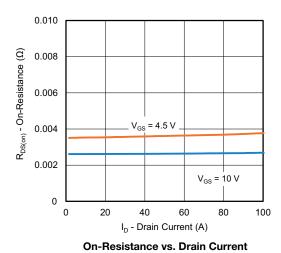
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

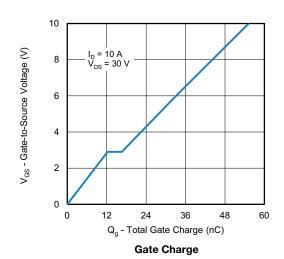






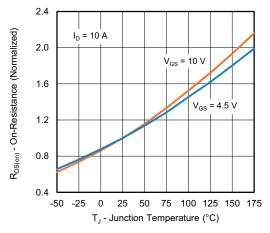




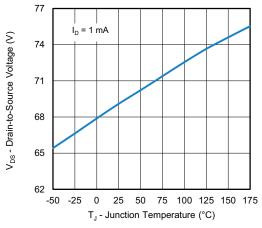




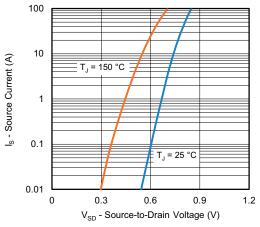
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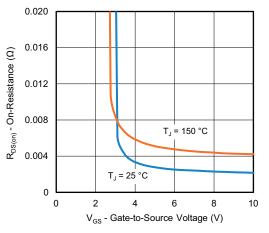
On-Resistance vs. Junction Temperature



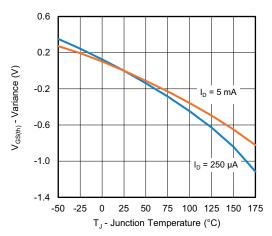
Drain Source Breakdown vs. Junction Temperature



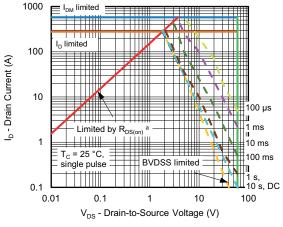
**Source Drain Diode Forward Voltage** 



On-Resistance vs. Gate-to Source Voltage



Threshold Voltage



Safe Operating Area

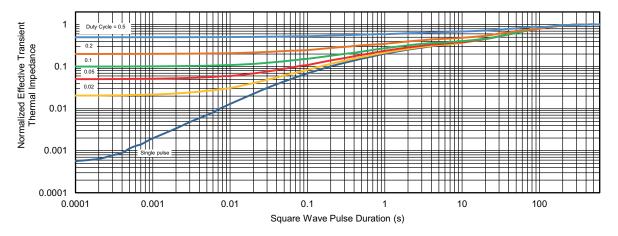
#### Note

a.  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

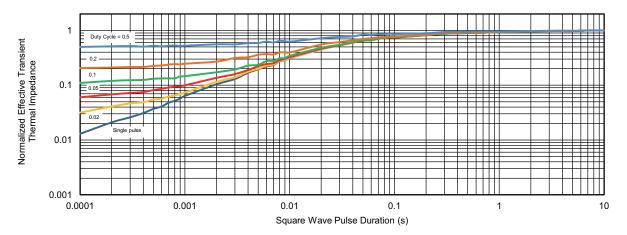
For technical questions, contact: automostechsu



## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

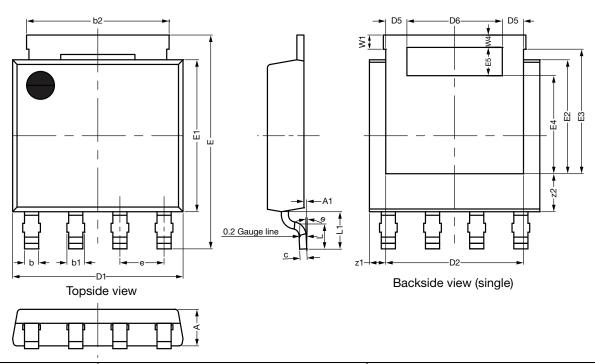


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76726.



# PowerPAK® SO-8L (PPKSO8LWLA) Case Outline 3



DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
A	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

ECN: C22-1223-Rev. C, 19-Dec-2022

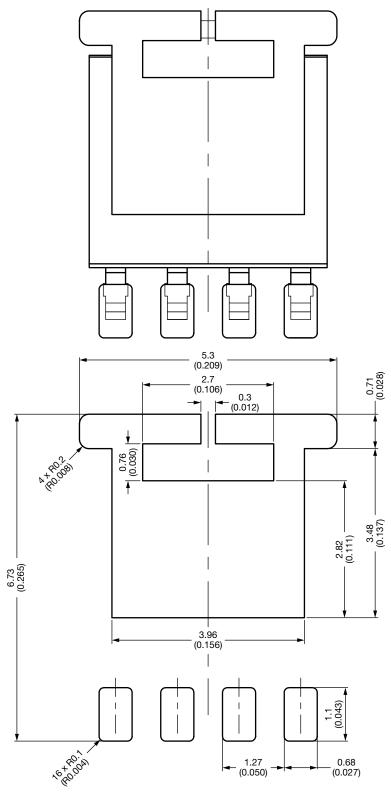
#### DWG: 6067 **Note**

Millimeter will govern

Revison: 19-Dec-2022 1 Document Number: 76666



# Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)



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